NSN 5961-00-004-5855

Transistor - Page 1 of 2



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Inclosure Material:

Metal

Overall Length:

Between 0.480 inches and 0.535 inches

Overall Diameter:

0.535 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.855 inches and 0.875 inches

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

180.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

30.00 amperes source cutoff current

Power Rating Per Characteristic:

86.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

NSN 5961-00-004-5855 Transistor - Page 2 of 2

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